Features

- Exceptional Broadband Performance, 0.05 6.0 GHz
- Low Loss: T_X = 0.33 dB @ 2010 MHz, 5V / 20mA
- T_X = 0.38 dB @ 3.5 GHz, 5V / 20mA
- High Isolation: Rx = 44dB @ 2010 MHz, 20mA / 5V
- Rx = 36dB @ 3.5 GHz, 20mA / 5V
- High T_x RF Input Power = 50 W C.W. @ 2010MHz
- High Tx RF Input Peak Power > 1000 W
- Suitable for Very High Power TD-SCDMA & WiMAX Applications
- Surface Mount 4mm PQFN Package, RoHS* Compliant

Description and Applications

The MASW-000834-13560T is a SPDT Broadband, high linearity, common anode, PIN diode T/R switch for 0.05 - 6.0 GHz applications, including WiMAX & WiFi. The device is provided in industry standard 4mm PQFN plastic packaging. This device incorporates a PIN diode die fabricated with M/A-COM Technology Solutions patented Silicon-Glass HMICTM process. This chip features two silicon pedestals embedded in a low loss, low dispersion glass. The diodes are formed on the top of each pedestal. The topside is fully encapsulated with silicon nitride and has an additional polymer passivation layer. These polymer protective coatings prevent damage and contamination during handling and assembly.

This compact 4mm PQFN package, SPDT switch offers wideband 0.05 - 6.0 GHz performance with excellent isolation to loss ratio for both $T_{\rm X}$ and $R_{\rm X}$ states. The PIN diode provides exceptional 50 W C.W. power handling and 65 dBm IIP3 at 2010 MHz for maximum switch performance.

Absolute Maximum Ratings¹

@ T_A = +25 °C (unless otherwise specified)

| Parameter | Absolute Maximum |
|------------------------------------|--|
| Forward Current | 100 mA |
| Reverse Voltage (RF & D.C.) | -200 V |
| Operating Temperature | -40 °C to +85 °C |
| Storage Temperature | -55 °C to +150 °C |
| Junction Temperature | +175 °C |
| T _x Incident C.W. Power | 50W (47 dBm) ² @ 2010MHz |
| T _X Peak Incident Power | >300 W, 5us, 1% duty |

1. Exceeding these limits may cause permanent damage.

2. Baseplate Temperature must be controlled to a constant +25°C. See page 7 for derating curve.

1

* Restrictions on Hazardous Substances, European Union Directive

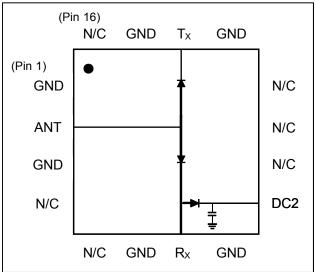
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Functional Diagram (TOP VIEW)



Pin Configuration:

(Center Metal Area is RF, D.C., and Thermal Ground)

| Pin | Function Pin Funct | | Function |
|-----|--------------------|----|----------|
| 1 | GND | 9 | DC2 |
| 2 | ANT | 10 | N/C |
| 3 | GND | 11 | N/C |
| 4 | N/C | 12 | N/C |
| 5 | N/C | 13 | GND |
| 6 | GND | 14 | ТХ |
| 7 | RX | 15 | GND |
| 8 | GND | 16 | N/C |

Ordering Information

| Part Number | Package |
|--------------------|--|
| MASW-000834-13560T | Tape and Reel |
| MASW-000834-001SMB | Sample Board |
| MADR-008851-0001TB | Sample Board with recommended external Driver & MASW-000834- 13560T Switch |

Static Sensitivity

These devices are rated Class 1B Human Body. Proper ESD control techniques should be used when handling these devices.

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Electrical Specifications at +25°C, Characteristic Impedance, 20mA / 5V, Z_0 = 50 Ω

| Parameter | Symbol | 20mA / 5V Conditions | Units | Min. | Тур. | Max. |
|---------------------------|-----------------------|--|-------|------|------|-------|
| F = 900 MHz | l I | | | | | |
| Insertion Loss, R_X | R _x IL | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | _ | 0.34 | 0.56 |
| Insertion Loss, T_X | T _X IL | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | _ | 0.26 | 0.445 |
| Isolation, ANT To R_{X} | R _x ISO | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | 45.8 | 52.1 | _ |
| Isolation, ANT To T_X | T _X ISO | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | 21.7 | 27.1 | _ |
| F = 1800 MHz | | | L | | | |
| Insertion Loss, R_X | R _X IL | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | _ | 0.40 | 0.72 |
| Insertion Loss, T_X | Tx IL | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | — | 0.32 | 0.49 |
| Isolation, ANT To R_X | Rx ISO | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | 43.7 | 48.9 | _ |
| Isolation, ANT To T_X | T _X ISO | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | 18.4 | 21.4 | |
| F = 2010 MHz | | | | | | |
| Insertion Loss, R_X | R _x IL | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | | 0.42 | 0.75 |
| Insertion Loss, T_X | T _X IL | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | _ | 0.33 | 0.5 |
| Isolation, ANT To R_X | R _X ISO | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | 43.2 | 44.6 | _ |
| Isolation, ANT To T_X | T _X ISO | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | 17.7 | 19.9 | |
| Input Return Loss, T_X | T _x RL | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | _ | 32.1 | _ |
| Input Return Loss, R_x | R _x RL | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | _ | 24.2 | _ |

2

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Electrical Specifications at +25°C, Characteristic Impedance, 20mA / 5V, Z_0 = 50 Ω

| Parameter | Symbol | 20mA / 5V Conditions | Units | Min. | Тур. | Max. |
|-----------------------------|-----------------------|--|-------|------|------|-------|
| F = 2.3-2.7 GHz | | | | | | |
| Insertion Loss, R_X | R _x IL | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | _ | 0.46 | 0.84 |
| Insertion Loss, T_X | T _X IL | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | _ | 0.35 | 0.525 |
| Isolation, ANT To R_X | R _x ISO | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | 40.2 | 41.2 | _ |
| Isolation, ANT To T_X | T _X ISO | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | 16.2 | 18.6 | _ |
| Input Return Loss, T_X | T _x RL | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | _ | 30.5 | _ |
| Input Return Loss, R_X | R _x RL | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | _ | 22.9 | _ |
| F = 3.3-3.8 GHz | | | | | | |
| Insertion Loss, $R_{\rm X}$ | R _x IL | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | | 0.56 | 1.0 |
| Insertion Loss, T_X | T _X IL | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | _ | 0.38 | 0.575 |
| Isolation, ANT To R_X | R _x ISO | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | 33.7 | 35.9 | _ |
| Isolation, ANT To T_{X} | T _X ISO | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | 13.6 | 16.1 | — |
| Input Return Loss, T_X | T _x RL | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | — | 27.4 | _ |
| Input Return Loss, R_X | R _x RL | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | _ | 21.9 | _ |
| F = 4.9-5.9 GHz | | | | | | |
| Insertion Loss, R_X | R _x IL | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | — | 0.78 | _ |
| Insertion Loss, T_X | T _X IL | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | | 0.52 | _ |
| Isolation, ANT To R_X | R _x ISO | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | _ | 26.4 | _ |
| Isolation, ANT To T_X | T _x ISO | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | | 11.8 | _ |
| Input Return Loss, T_X | T _x RL | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | | 20.3 | _ |
| Input Return Loss, R_x | R _x RL | See Bias Table 1, pg. 10, Pinc= 0 dBm | dB | | 24.2 | _ |

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Electrical Specifications at +25°C, Characteristic Impedance, 50mA / 25V, $Z_0 = 50 \Omega$

| Parameter | Symbol | 50mA / 25V Conditions | Units | Min. | Тур. | Max. |
|-----------------------------------|-----------------------|--|-------|------|------|------|
| F = 900 MHz | L | | | | I | I |
| Insertion Loss, R_X | R _x IL | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | _ | 0.27 | _ |
| Insertion Loss, T_X | T _X IL | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | _ | 0.22 | _ |
| Isolation, ANT To R_X | R _X ISO | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | _ | 53.3 | _ |
| Isolation, ANT To T_X | T _X ISO | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | _ | 27.4 | _ |
| F = 1800 MHz | | | | | | |
| Insertion Loss, R_X | R _x IL | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | | 0.32 | |
| Insertion Loss, T_X | T _X IL | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | _ | 0.27 | _ |
| Isolation, ANT To R_{X} | R _x ISO | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | _ | 50.2 | _ |
| Isolation, ANT To T_{X} | T _X ISO | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | _ | 21.6 | _ |
| F = 2010 MHz | | | | | | |
| Insertion Loss, R_X | R _x IL | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | _ | 0.34 | |
| Insertion Loss, T_X | T _X IL | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | _ | 0.28 | _ |
| Isolation, ANT To R_{X} | R _x ISO | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | — | 45.5 | — |
| Isolation, ANT To T_X | T _X ISO | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | _ | 20.1 | — |
| Input Return Loss, T_X | T _x RL | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | _ | 33.1 | — |
| Input Return Loss, R _X | R _x RL | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | _ | 24.1 | _ |

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Electrical Specifications at +25°C, Characteristic Impedance, 50mA / 25V, $Z_0 = 50 \Omega$

| | | • | | | | |
|--------------------------------|-----------------------|--|-------|------|------|------|
| Parameter | Symbol | 50mA / 25V Conditions | Units | Min. | Тур. | Max. |
| F = 2.3-2.7 GHz | 1 1 | | I | | | |
| Insertion Loss, R_X | R _x IL | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | | 0.38 | _ |
| Insertion Loss, T_X | T _X IL | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | | 0.30 | _ |
| Isolation, ANT To R_X | R _x ISO | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | | 41.8 | _ |
| Isolation, ANT To T_X | T _X ISO | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | | 18.7 | _ |
| Input Return Loss, T_X | T _X RL | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | | 31.3 | _ |
| Input Return Loss, R_X | R _x RL | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | | 22.8 | — |
| F = 3.3-3.8 GHz | | | | I | | 1 |
| Insertion Loss, R_X | R _x IL | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | — | 0.47 | _ |
| Insertion Loss, T_X | T _X IL | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | | 0.33 | _ |
| Isolation, ANT To R_X | R _x ISO | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | _ | 36.2 | _ |
| Isolation, ANT To T_X | T _X ISO | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | | 16.2 | _ |
| Input Return Loss, T_X | T _X RL | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | _ | 28.0 | _ |
| Input Return Loss, R_X | R _x RL | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | | 21.8 | _ |
| F = 4.9-5.9 GHz | L L | | I | | | |
| Insertion Loss, R _x | R _x IL | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | | 0.72 | |
| Insertion Loss, T_X | T _X IL | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | | 0.48 | _ |
| Isolation, ANT To R_X | R _X ISO | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | | 26.6 | — |
| Isolation, ANT To T_X | T _X ISO | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | — | 11.8 | _ |
| Input Return Loss, T_X | T _X RL | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | _ | 20.5 | _ |
| Input Return Loss, R_x | R _X RL | See Bias Table 2, pg. 10, Pinc= 0 dBm | dB | | 24.2 | _ |

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Watt Switch for



Rev. V7

HMIC[™] PIN Diode SPDT 50 Watt Switch for 0.05 - 6.0 GHz Higher Power Applications

Electrical Specifications at +25°C, Characteristic Impedance, 50mA / 25V, $Z_0 = 50 \Omega$

| Parameter | Symbol | 50mA / 25V Conditions | Units | Min. | Тур. | Max. |
|---|------------------------|---|----------|------|-------|------------|
| T _X Input P1dB ² | T _X P1dB | 2010 MHz, T _x to Antenna | dBm | _ | >45.5 | _ |
| T _X 2 nd Harmonic | T _X 2Fo | 2010 MHz, Pin = + 30 dBm | dBc | _ | 80 | _ |
| T _x 3 rd Harmonic | T _X 3Fo | 2010 MHz, Pin = + 30 dBm | dBc | | 95 | |
| T _X Input Third Order Intercept Point | T _X IIP3 | Pi= +10dBm, F1 = 2010 MHz, F2 = 2020 MHz | dBm | | >64 | |
| T _X C.W. Input Power ² | T _x Pinc | F = 2010 MHz | dBm W | _ | _ | 47 50 |
| R _x C.W. Input Power | R _x Pinc | F = 2010 MHz | dBm W | _ | | 41.5 14 |
| T _X RF Switching Speed | t _{RF} | F = 2010 MHz (10-90% RF Voltage) 1MHz Rep Rate in Modulating Mode | ns | — | 200 | — |

| Parameter | Symbol | 50mA / 25V Conditions | Units | Min. | Тур. | Max. |
|---|------------------------|--|----------|------|------|------------|
| T _x Input P1dB | T _x P1dB | 3.5 GHz, T_X to Antenna | dBm | | >45 | — |
| T _X 2 nd Harmonic | T _X 2Fo | 3.5 GHz, Pin = + 30 dBm | dBc | | 88 | — |
| T _X 3 rd Harmonic | T _X 3Fo | 3.5 GHz, Pin = + 30 dBm | dBc | - | 105 | _ |
| T _X Input Third Order Intercept Point | T _X IIP3 | Pi= +10dBm, F1 = 3.500 GHz, F2 = 3.510 GHz | dBm | _ | >64 | |
| R _x C.W. Input Power | R _x Pinc | F = 3.5 GHz | dBm W | _ | _ | 40.5 11 |
| T _x RF Switching Speed | t _{RF} | F = 3.5 GHz (10-90% RF Voltage) 1MHz Rep Rate in Modulating Mode | ns | _ | 200 | _ |

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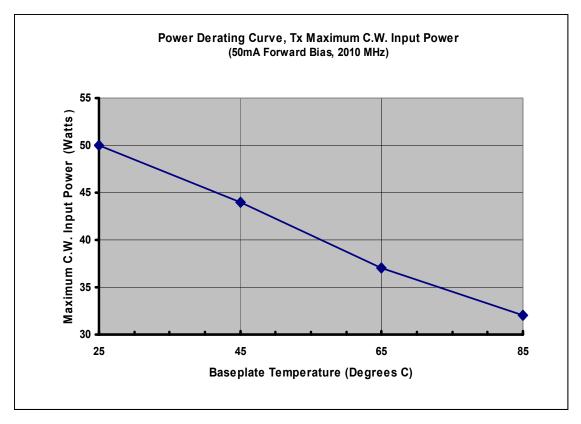
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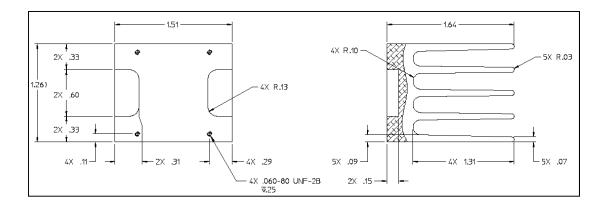
HMIC[™] PIN Diode SPDT 50 Watt Switch for 0.05 - 6.0 GHz Higher Power Applications

Electrical Specifications at +25°C, Characteristic Impedance, 50mA / 25V, $Z_0 = 50 \Omega$



Note that this part must be held to a constant baseplate temperature to achieve the power handling results specified above. Adding a heatsink to the baseplate will improve performance to values greater than shown here. The increase in maximum input power from using a heatsink depends on the specific heatsink design.

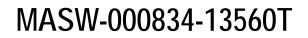
With a sample board mounted onto a heatsink of dimensions and fins shown below, this switch can handle up to 35 Watts C.W. of incident power.



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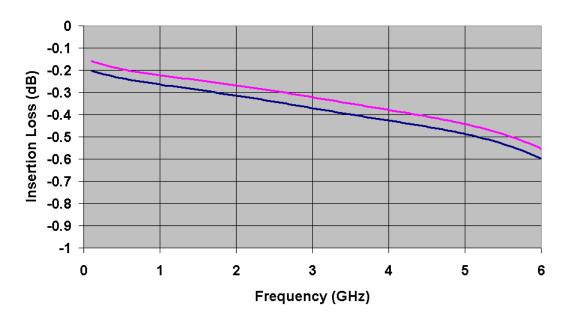
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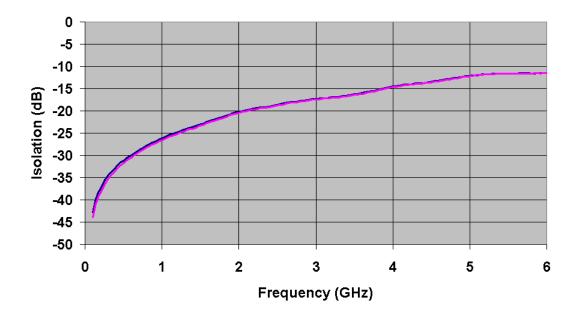
HMIC[™] PIN Diode SPDT 50 Watt Switch for 0.05 - 6.0 GHz Higher Power Applications

T_X Performance Curves at +25°C, Characteristic Impedance, $Z_0 = 50 \Omega$



Tx Insertion Loss 20mA & 50mA Forward Bias

Tx Isolation 5V & 25V Reverse Bias



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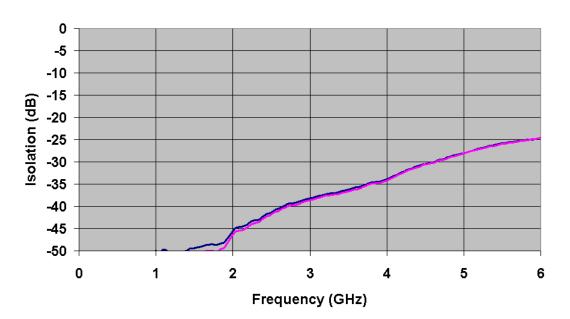




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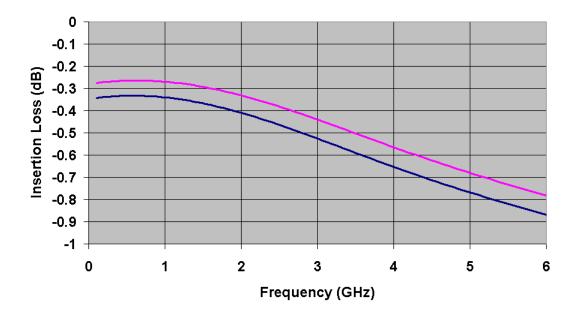
HMIC[™] PIN Diode SPDT 50 Watt Switch for 0.05 - 6.0 GHz Higher Power Applications

R_X Performance Curves at +25°C, Characteristic Impedance, $Z_0 = 50 \Omega$





Rx Insertion Loss 20mA & 50mA Forward Bias

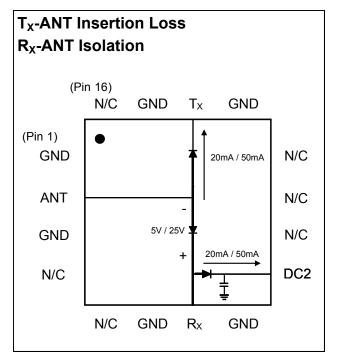


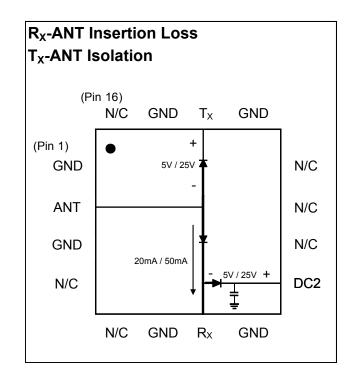
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Bias Diagrams & Tables





| Bias Table 1 | T _x | R _X | DC2 | ANT |
|------------------------------------|----------------|----------------|-----------|-------|
| | Pin 14 | Pin 7 | Pin 9 | Pin 2 |
| T _x -ANT Insertion Loss | -20 mA | +5V, 0 mA | -20 mA | 0V |
| R _x -ANT Isolation | | | | |
| R _x -ANT Insertion Loss | +5V, 0 mA | -20 mA | +5V, 0 mA | 0V |
| T _x -ANT Isolation | | | | |

| Bias Table 2 | T _x | R _x | DC2 | ANT |
|------------------------------------|----------------|----------------|------------|-------|
| | Pin 14 | Pin 7 | Pin 9 | Pin 2 |
| T _x -ANT Insertion Loss | -50 mA | +25V, 0 mA | -50 mA | 0V |
| R _x -ANT Isolation | | | | |
| R _x -ANT Insertion Loss | +25V, 0 mA | -50 mA | +25V, 0 mA | 0V |
| T _x -ANT Isolation | | | | |

*Note - Diode Based Products require different minimum reverse bias voltages depending on the frequency and incident power levels. More details can be found on page 11 of this datasheet.

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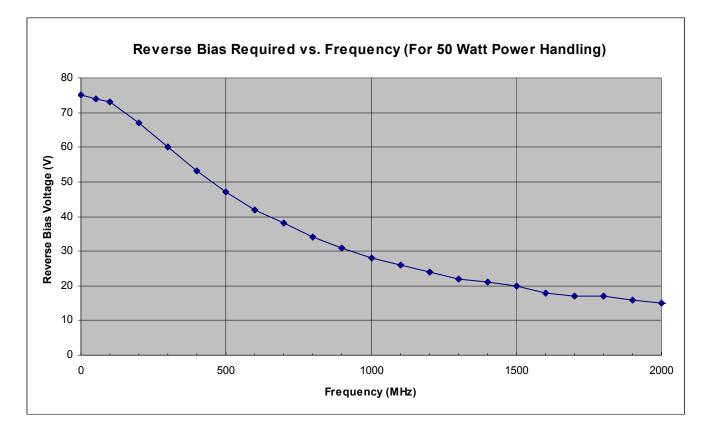


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MASW-000834 Minimum Required Reverse Bias Voltage

Minimum reverse bias voltage on a PIN diode based product varies with frequency of operation and incident power levels. As a rule of thumb, a designer can always use the magnitude of the peak RF voltage or empirically locate lower bias values than the peak RF voltage magnitude. However, it has been shown that lower DC voltages can be used depending on the RF environment in which a diode is placed. In the plot below, the minimum required reverse voltage vs. frequency is shown for an incident RF power of 50 Watts. This trend line will shift lower if the incident RF power is decreased. The biasing values have not been verified through measurement at M/A-COM Technology Solutions. As a result, please use the data below as a guide only for biasing requirements as this data is based solely on generic PIN diode equations.³

Please be cautious in that lower reverse bias levels can degrade isolation and distortion in a PIN diode based product.



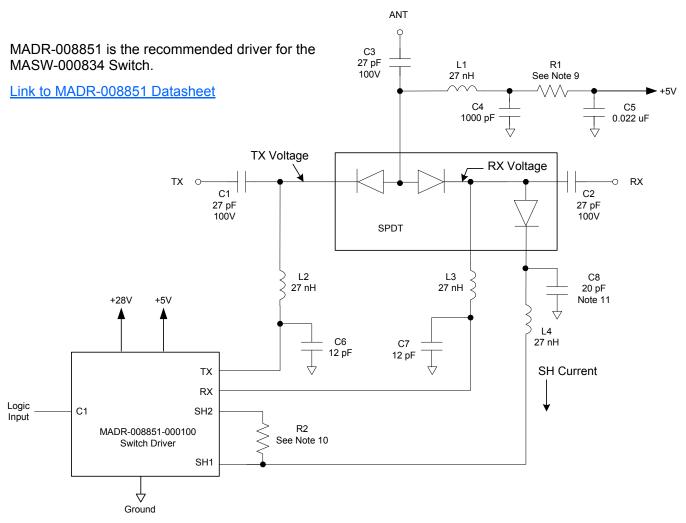
[3] R. Caverly and G. Hiller, "Establishing the Minimum Reverse Bias for a P-I-N Diode in a High Power Switch," *IEEE Transactions on Microwave Theory and Techniques*, Vol.38, No.12, December 1990

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MASW-000834 and Recommended Driver with +5V & +28V DC Power^{4,5,6,7,8,9,10,11}



- 4. Forward Bias Diode Voltage: Δ Vf is ~0.9V @ 22 mA; Δ Vf is ~1.0V @ 35 mA
- 5. R1 is calculated by (Vcc-1.5V)/I_{series}, where I_{series} is the desired bias current for the series diodes. For 21 mA load current, R1 = 165 Ω @ VCC = 5.0V and 82 Ω @ VCC = 3.3V. For 32 mA load current, R1 = 110 Ω @ VCC = 5.0V and 56 Ω @ VCC = 3.3V.
- R2 is calculated by (Vdd-1V)/I_{shunt}, where I_{shunt} is the desired forward bias current for the shunt diode. The power dissipation is calculated by I_{shunt} x 27V. For 20 mA of I_{shunt}, R2 should use a 2511, 1W, 1.3k ohm resistor.
- 7. C8 is already built-in for M/A-COM MASW-000834-13560T switch.
- 8. The voltage at the common anode will be approximately 1.5V.
- 9. The current in through the back-biased diodes will be the leakage current for the diodes
- 10. C1-C5, L1-L4, R1, R2, and the switch are discrete components that should be installed on the user's board. It is recommended that Coilcraft 0603CS-27NXJLW or equivalent be used for L1-L4 at 2 GHz (values may vary based on the frequency).
- 11. There are 33 pF bypass capacitors included in the driver for the RX, TX, and SH1 ports. There are cases, especially at higher frequencies, where the optional 12 pF bypass capacitors (C6 and C7) that are shown on the schematic are needed.

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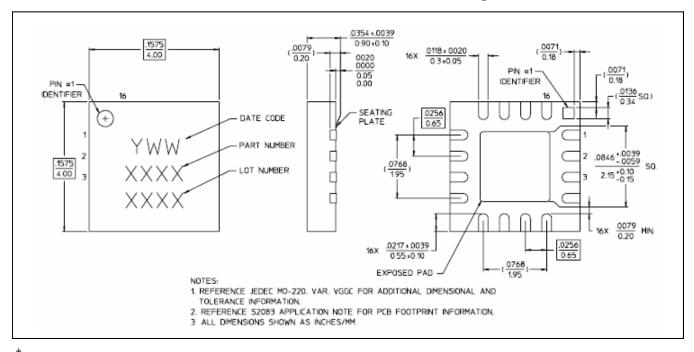
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MASW-000834-13560T Outline – 4mm PQFN 16-Lead Saw Singulated



⁺ Reference Application Note S2083 for lead-free solder reflow recommendations. Meets JEDEC moisture sensitivity level 1 requirements.

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